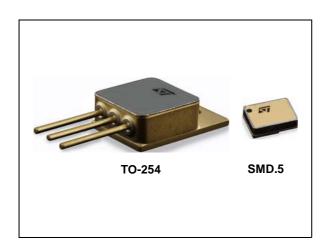


STPS20100HR

Aerospace 1 x 20 and 2 x 20 A - 100 V Schottky rectifier

Datasheet - production data



Features

- Forward current: 1 x 20 and 2 x 20 A
- Repetitive peak voltage: 100 V
- Low forward voltage drop: 0.8 V
- Maximum junction temperature: 175 °C
- Negligible switching losses
- Low capacitance

- High reverse avalanche surge capability
- · Hermetic packages
- Target radiation qualification:
 - 150 krad (Si) low dose rate
 - 1 Mrad high dose rate
- · ESCC qualified

Description

This power Schottky rectifier is designed and packaged to comply with the ESCC5000 specification for aerospace products. Housed in hermetically sealed packages both surface mount and through hole, it is ideal for use in applications for aerospace and other harsh environments.

The STPS20100HR is intended for use in medium voltage application and particularly, in high frequency circuits where low switching losses and low noise are required.

Table 1. Device summary

Order code	ESCC detailed specification	Quality level	Package	EPPL	lf (AV)	VRRM	Tj (max)	VF (max)
STPS20100S1	-	Engineering model	SMD.5	-	1 x 20	100	175	1
STPS20100A2FY1	-	Engineering model	TO-254	-	2 x 20			
STPS20100C2FY1	-	Engineering model	TO-254	-	2 x 20			
STPS20100SG	5106/016/05	ESCC Flight	SMD.5	Yes	1 x 20			
STPS20100A2FYT	5106/016/02	ESCC Flight	TO-254	-	2 x 20			
STPS20100C2FYT	5106/016/03	ESCC Flight	TO-254	-	2 x 20			
STPS20100FYT	5106/016/01	ESCC Flight	TO-254	-	1 x 20			

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1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Characteristic	Value	Unit
I _{FSM}	Forward surge current (per diode) ⁽¹⁾	250	Α
V _{RRM}	Repetitive peak reverse voltage ⁽²⁾	100	V
I _{RRM}	Repetitive peak reverse current ⁽³⁾	1	А
I _o	Average output rectified current (50% duty cycle): ⁽⁴⁾ , ⁽⁵⁾ All variants (per diode) Variants 02, and 03 (per device)	20 40	А
I _{F(RMS)}	Forward rms current (per diode)	30	А
T _{OP}	Operating temperature range ⁽⁶⁾ (case temperature)	-65 to +175	°C
T _J	Junction temperature	+175	°C
T _{STG}	Storage temperature range ⁽⁶⁾	-65 to +175	°C
T _{SOL}	Soldering temperature: For TO-254 ⁽⁷⁾ For SMD.5 ⁽⁸⁾	+260 +245	οС
dV/dt	Critical rate of rise of reverse voltage	10000	V/µs

- 1. Sinusoidal pulse of 10 ms duration
- 2. Pulsed, duration 5 ms, F = 50 Hz
- 3. Pulsed, duration 2 μ s, F = 1 kHz
- 4. For $T_{case} > +140$ °C, derate linearly to 0 A at +175 °C.
- The "per Device" ratings apply only as follows: Variant 02: when both cathode terminals are tied together Variant 03: when both anode terminals are tied together.
- 6. For variants with hot solder dip lead finish all testing performed at T_{amb} > +125 °C are carried out in a 100% inert atmosphere.
- Duration 10 seconds maximum at a distance of not less than 1.5 mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 8. Duration 5 seconds maximum and the same package shall not be resoldered until 3 minutes have elapsed.

Table 3. Thermal resistance

Symbol	Characteristic	Value	Unit
R _{th(j-c)} ⁽¹⁾	Thermal resistance, junction to case Variants 01, and 05 Variants 02 and 03 (per diode) Variants 02, and 03 (per device) ⁽²⁾	1.65 1.65 0.85	°C/W

- 1. Package mounted on infinite heatsink
- 2. The per device ratings apply for variant 02 when both cathode terminals are tied together and for variant 03 when both anode terminals are tied together.

STPS20100HR Characteristics

Table 4. Electrical measurements at ambiant temperature (per diode), T_{amb} = 22 ± 3 °C

Cumbal	Characteristic	MIL-STD-750	Test conditions	Val	Units	
Symbol Char	Characteristic	test method	rest conditions	Min.	Max.	Office
I _R	Reverse Current	4016	DC method, V _R = 100 V	-	30	μΑ
V _{F1} ⁽¹⁾	Forward Voltage	4011	Pulse method, I _F = 10 A	-	780	mV
V _{F2} ⁽¹⁾	Polward voltage	4011	Pulse method, I _F = 20 A	-	1	V
С	Capacitance	4001	V _R = 10 V, F = 1 MHz	-	700	pF
$Z_{\text{th(j-c)}}$	Relative thermal impedance, junction to case	3101	$I_H = 15 \text{ to } 40 \text{ A}, t_H = 50 \text{ ms}$ $I_M = 50 \text{ mA}, t_{md} = 100 \mu\text{s}$	Calcula	ate ∆V _F	°C/W

^{1.} Pulse width \leq 680 μ s, Duty Cycle \leq 2%

Table 5. Electrical measurements at high and low temperatures (per diode)

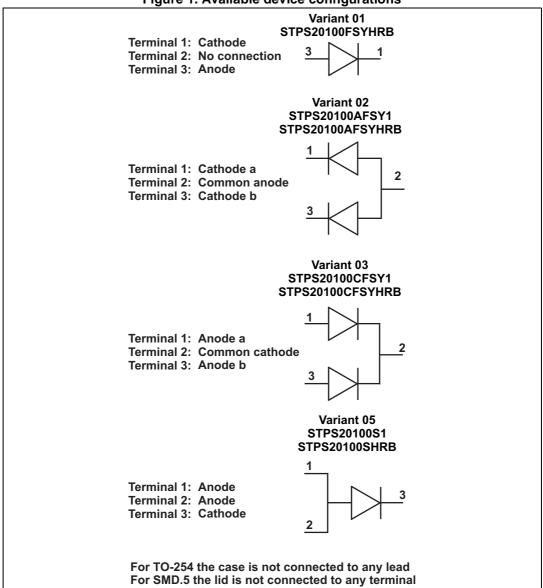
Symbol	Characteristic	MIL-STD-750	Test conditions	Values		- Units
Symbol Characteristic		test method	rest conditions	Min.	Max.	
I _R	Reverse Current	4016	$T_{case} = +125 (+0, -5) ^{\circ}C$ DC method, $V_{R} = 100 V$	-	20	mA
V (1)	Forward Voltage	4011	T_{case} = +125 (+0, -5) °C pulse method, I_F = 20 A	-	900	mV
V _{F2} ⁽¹⁾ Forward Voltage	4011	T_{case} = -55 (+5, -0) °C pulse method, I_F = 20 A	1	1.1	V	

^{1.} Pulse width ≤ 680µs, Duty Cycle ≤ 2%

Configurations STPS20100HR

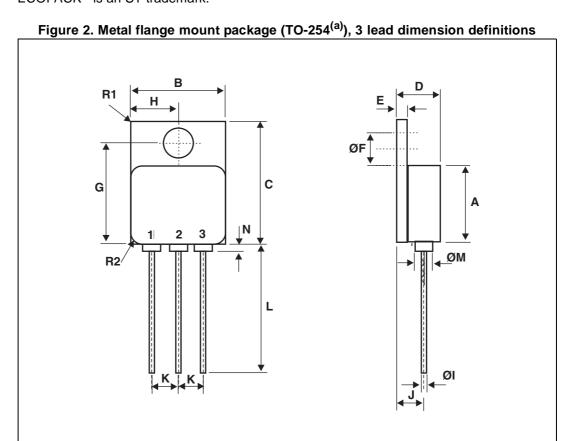
2 Configurations

Figure 1. Available device configurations



3 Package Information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



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a. The terminal identification is specified by the device configuration. See *Figure 1* for terminal connections

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Table 6. Metal flange mount package (TO-254), 3-lead dimension values

Reference	Dimension in	n millimetres	Dimlension in inches		
Reference	Min.	Max.	Min.	Max.	
А	13.59	13.84	0.535	0.545	
В	13.59	13.84	0.535	0.545	
С	20.07	20.32	0.790	0.800	
D	6.3	6.7	0.248	0.264	
E	1	3.9	0.039	0.154	
ØF	3.5	3.9	0.138	0.154	
G	16.89	17.4	0.665	0.685	
Н	6.86	BSC	0.270 BSC		
ØI ⁽¹⁾	0.89	1.14	0.035	0.045	
J	3.81	BSC	0.150 BSC		
К	3.81	BSC	0.150 BSC		
L	12.95	14.5	0.510	0.571	
ØM	3.05 Typ.		0.120	Тур.	
N	-	0.71	-	0.028	
R1 ⁽²⁾	-	1	-	0.039	
R2 ⁽³⁾	1.65	Тур.	0.065		

^{1. 3} locations

^{2.} Radius of heatsink flange corner - 4 locations

^{3.} Radius of body corner - 4 locations

Figure 3. Surface mount package (SMD.5), 3-terminal dimension definitions

Table 7. Surface mount package (SMD.5), 3-terminal dimension values

Reference	Dimension in	n millimetres	Dimlension in inches		
Reference	Min.	Max.	Min.	Max.	
Α	2.84	3.15	0.112	0.124	
A1	0.25	0.51	0.010	0.20	
b	7.13	7.39	0.281	0.291	
b1	5.58	5.84	0.220	0.230	
b2 ⁽¹⁾	2.28	2.54	0.090	0.100	
b3 ⁽¹⁾	2.92	3.18	0.115	0.125	
D	10.03	10.28	0.395	0.405	
D1 ⁽¹⁾	0.76	-	0.030	-	
E	7.39	7.64	0.291	0.301	
e ⁽¹⁾	1.91	BSC	0.0	75	

^{1. 2} locations

Ordering information STPS20100HR

4 Ordering information

Table 8. Ordering information

Order code	ESCC detailed specification	Package	Lead finish	Comment	Marking ⁽¹⁾	Mass	EPPL	Packing
STPS20100S1	-	SMD.5	Gold	Single die	STPS20100S1	2	-	
STPS20100A2FY1	-	TO-254	Gold	Double die - common anode	STPS20100AFY1 + BeO	10	-	
STPS20100C2FY1	-	TO-254	Gold	Double die - common cathode	STPS20100CFY1 + BeO	10	-	
STPS20100SG	5106/016/05	SMD.5	Gold	Single die	510601605	2	Yes	Strip
STPS20100A2FYT	5106/016/02	TO-254	Solder Dip	Double die - common anode	510601602 +BeO	10	-	pack
STPS20100C2FYT	5106/016/03	TO-254	Solder Dip	Double die - common cathode	510601603 +BeO	10	-	
STPS20100FYT	5106/016/01	TO-254	Solder Dip	Single die	510601601 +BeO	10	-	

Specific marking only. The full marking includes in addition: For the engineering models: ST logo, date code, country of origin (FR). For ESCC flight parts: ST logo, date code, country of origin (FR), ESA logo, serial number of the part within the assembly lot.

5 Revision history

Table 9. Document revision history

Date	Revision	Changes
25-Mar-2010	1	Initial release.
19-Mar-2014	2	Updated Table 1: Device summary, Table 8: Ordering information and Figure 1: Available device configurations.

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